

T-79-09



**MC1776  
MC1776C**

**Specifications and Applications  
Information**

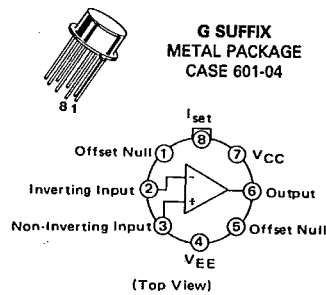
**MONOLITHIC MICROPOWER  
PROGRAMMABLE OPERATIONAL AMPLIFIER**

This extremely versatile operational amplifier features low power consumption and high input impedance. In addition, the quiescent currents within the device may be programmed by the choice of an external resistor value or current source applied to the  $I_{set}$  input. This allows the amplifier's characteristics to be optimized for input current and power consumption despite wide variations in operating power supply voltages.

- $\pm 1.2$  V to  $\pm 18$  V Operation
- Wide Programming Range
- Offset Null Capability
- No Frequency Compensation Required
- Low Input Bias Currents
- Short-Circuit Protection

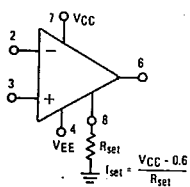
**PROGRAMMABLE  
OPERATIONAL AMPLIFIER**

**SILICON MONOLITHIC  
INTEGRATED CIRCUIT**



**RESISTIVE PROGRAMMING (See Figure 1.)**

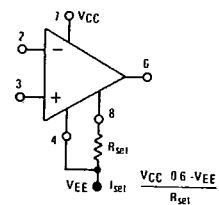
**$R_{set}$  to GROUND**



**Typical  $R_{set}$  Values**

$V_{CC}, V_{EE}$	$I_{set} = 1.5 \mu A$	$I_{set} = 15 \mu A$
$\pm 6.0V$	3.6 M $\Omega$	360 k $\Omega$
$\pm 10V$	6.2 M $\Omega$	620 k $\Omega$
$\pm 12V$	7.5 M $\Omega$	750 k $\Omega$
$\pm 15V$	10 M $\Omega$	1.0 M $\Omega$

**$R_{set}$  to NEGATIVE SUPPLY  
(Recommended for supply voltage  
less than  $\pm 6.0$  V)**

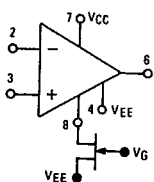


**Typical  $R_{set}$  Values**

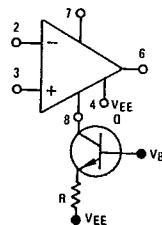
$V_{CC}, V_{EE}$	$I_{set} = 1.5 \mu A$	$I_{set} = 15 \mu A$
$\pm 1.5V$	1.6 M $\Omega$	160 k $\Omega$
$\pm 3.0V$	3.6 M $\Omega$	360 k $\Omega$
$\pm 6.0V$	7.5 M $\Omega$	750 k $\Omega$
$\pm 15 V$	20 M $\Omega$	2.0 M $\Omega$

**ACTIVE PROGRAMMING**

**FET CURRENT SOURCE**



**BIPOLAR CURRENT SOURCE**

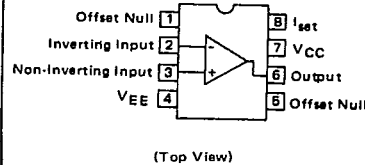


Pins not shown are not connected.

**P1 SUFFIX  
PLASTIC PACKAGE  
CASE 626-05  
(MC1776C Only)**

**U SUFFIX  
CERAMIC PACKAGE  
CASE 693-02**

**D SUFFIX  
PLASTIC PACKAGE  
CASE 751-02  
SO-8**



**ORDERING INFORMATION**

Device	Temperature Range	Package
MC1776G	-55 to +125°C	Metal Can
MC1776U		Ceramic DIP
MC1776CD	0 to +70°C	SO-8
MC1776CG		Metal Can
MC1776CP1		Plastic DIP
MC1776CU		Ceramic DIP

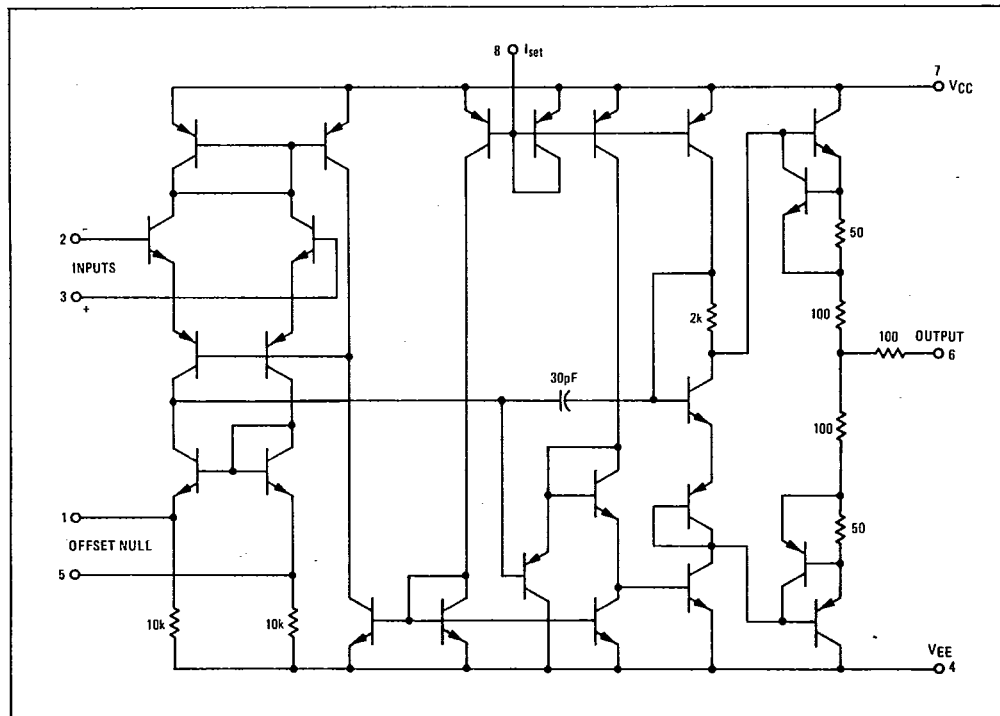
**MC1776, MC1776C**

MAXIMUM RATINGS ( $T_A = +25^\circ\text{C}$  unless otherwise noted.)

Rating	Symbol	Value	Unit
Power Supply Voltages	$V_{CC}, V_{EE}$	$\pm 18$	Vdc
Differential Input Voltage	$V_{ID}$	$\pm 30$	Vdc
Common-Mode Input Voltage $V_{CC}$ and $ V_{EE}  < 15\text{ V}$ $V_{CC}$ and $ V_{EE}  \geq 15\text{ V}$	$V_{ICM}$	$V_{CC}, V_{EE}$ $\pm 15$	Vdc
Offset Null to VEE Voltage	$V_{off-V_{EE}}$	$\pm 0.5$	Vdc
Programming Current	$I_{set}$	500	$\mu\text{A}$
Programming Voltage (Voltage from $I_{set}$ terminal to ground)	$V_{set}$	$(V_{CC} - 2.0\text{ V})$ to $V_{CC}$	Vdc
Output Short-Circuit Duration*	$t_s$	Indefinite	s
Operating Temperature Range	$T_A$	-55 to +125 0 to +70	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	-65 to +150 -55 to +125	$^\circ\text{C}$
Junction Temperature	$T_J$	175 150	$^\circ\text{C}$

\*May be to ground or either Supply Voltage. Rating applies up to a case temperature of  $+125^\circ\text{C}$  or ambient temperature of  $+70^\circ\text{C}$  and  $I_{set} \leq 30\ \mu\text{A}$ .

SCHMATIC DIAGRAM

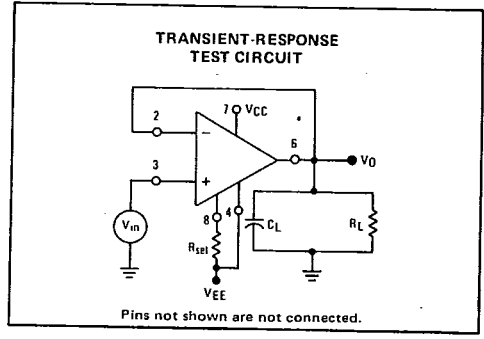
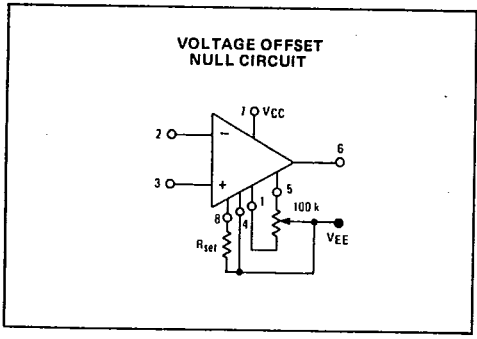


MC1776, MC1776C

ELECTRICAL CHARACTERISTICS (VCC = +3.0 V, VEE = -3.0 V, I<sub>set</sub> = 1.5 μA, T<sub>A</sub> = +25°C unless otherwise noted.)

Characteristic	Symbol	MC1776			MC1776C			Unit
		Min	Typ	Max	Min	Typ	Max	
Input Offset Voltage (R <sub>S</sub> ≤ 10 kΩ) T <sub>A</sub> = +25°C T <sub>low</sub> * ≤ T <sub>A</sub> ≤ T <sub>high</sub> *	V <sub>IO</sub>	-	2.0	5.0	-	2.0	6.0	mV
		-	-	6.0	-	-	7.5	
Offset Voltage Adjustment Range	V <sub>IOR</sub>	-	9.0	-	-	9.0	-	mV
Input Offset Current T <sub>A</sub> = +25°C T <sub>A</sub> = T <sub>high</sub> T <sub>A</sub> = T <sub>low</sub>	I <sub>IO</sub>	-	0.7	3.0	-	0.7	6.0	nA
		-	-	5.0	-	-	6.0	
		-	-	10	-	-	10	
Input Bias Current T <sub>A</sub> = +25°C T <sub>A</sub> = T <sub>high</sub> T <sub>A</sub> = T <sub>low</sub>	I <sub>IB</sub>	-	2.0	7.5	-	2.0	10	nA
		-	-	7.5	-	-	10	
		-	-	20	-	-	20	
Input Resistance	r <sub>i</sub>	-	50	-	-	50	-	MΩ
Input Capacitance	C <sub>i</sub>	-	2.0	-	-	2.0	-	pF
Input Voltage Range T <sub>low</sub> ≤ T <sub>A</sub> ≤ T <sub>high</sub>	V <sub>ID</sub>	+1.0	-	-	±1.0	-	-	V
Large Signal Voltage Gain R <sub>L</sub> ≥ 75 kΩ, V <sub>O</sub> = ±1.0 V, T <sub>A</sub> = +25°C R <sub>L</sub> ≥ 75 kΩ, V <sub>O</sub> = ±1.0 V, T <sub>low</sub> ≤ T <sub>A</sub> ≤ T <sub>high</sub>	AVOL	50 k	200 k	-	25 k	200 k	-	V/V
		25 k	-	-	25 k	-	-	
Output Voltage Swing R <sub>L</sub> ≥ 75 kΩ, T <sub>low</sub> ≤ T <sub>A</sub> ≤ T <sub>high</sub>	V <sub>O</sub>	±2.0	±2.4	-	±2.0	±2.4	-	V
Output Resistance	r <sub>o</sub>	-	5.0	-	-	5.0	-	kΩ
Output Short-Circuit Current	I <sub>OS</sub>	-	3.0	-	-	3.0	-	mA
Common-Mode Rejection Ratio R <sub>S</sub> ≤ 10 kΩ, T <sub>low</sub> ≤ T <sub>A</sub> ≤ T <sub>high</sub>	CMRR	70	86	-	70	86	-	dB
Supply Voltage Rejection Ratio R <sub>S</sub> ≤ 10 kΩ, T <sub>low</sub> ≤ T <sub>A</sub> ≤ T <sub>high</sub>	PSRR	-	25	150	-	25	200	μV/V
Supply Current T <sub>A</sub> = +25°C T <sub>low</sub> ≤ T <sub>A</sub> ≤ T <sub>high</sub>	I <sub>CC</sub> , I <sub>EE</sub>	-	13	20	-	13	20	μA
		-	-	25	-	-	25	
Power Dissipation T <sub>A</sub> = +25°C T <sub>low</sub> ≤ T <sub>A</sub> ≤ T <sub>high</sub>	P <sub>D</sub>	-	78	120	-	78	120	μW
		-	-	150	-	-	150	
Transient Response (Unity Gain) V <sub>in</sub> = 20 mV, R <sub>L</sub> ≥ 5.0 kΩ, C <sub>L</sub> = 100 pF								
Rise Time	t <sub>TLH</sub>	-	3.0	-	-	3.0	-	μs
Overshoot	OS	-	0	-	-	0	-	%
Slew Rate (R <sub>L</sub> ≥ 5.0 kΩ)	S <sub>R</sub>	-	0.03	-	-	0.03	-	V/μs

\*T<sub>low</sub> = -55°C for MC1776  
0°C for MC1776C  
T<sub>high</sub> = +125°C for MC1776  
+70°C for MC1776C



MC1776, MC1776C

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ELECTRICAL CHARACTERISTICS ( $V_{CC} = +3.0V$ ,  $V_{EE} = -3.0V$ ,  $I_{set} = 15\mu A$ ,  $T_A = +25^\circ C$  unless otherwise noted.)

Characteristic	Symbol	MC1776			MC1776C			Unit
		Min	Typ	Max	Min	Typ	Max	
Input Offset Voltage ( $R_S < 10k\Omega$ ) $T_A = +25^\circ C$ $T_{low} < T_A < T_{high}^*$	$V_{IO}$	-	2.0	5.0	-	2.0	6.0 7.5	mV
Offset Voltage Adjustment Range	$V_{IOR}$	-	18	-	-	18	-	mV
Input Offset Current $T_A = +25^\circ C$ $T_A = T_{high}$ $T_A = T_{low}$	$I_{IO}$	-	2.0	15	-	2.0	25 25 40	nA
Input Bias Current $T_A = +25^\circ C$ $T_A = T_{high}$ $T_A = T_{low}$	$I_{IB}$	-	15	50	-	15	50 50 100	nA
Input Resistance	$r_i$	-	5.0	-	-	5.0	-	M $\Omega$
Input Capacitance	$c_i$	-	2.0	-	-	2.0	-	pF
Input Voltage Range $T_{low} < T_A < T_{high}$	$V_{ID}$	$\pm 1.0$	-	-	$\pm 1.0$	-	-	V
Large Signal Voltage Gain $R_L > 5.0k\Omega$ , $V_O = \pm 1.0V$ , $T_A = +25^\circ C$ $R_L > 5.0k\Omega$ , $V_O = \pm 1.0V$ , $T_{low} < T_A < T_{high}$	$A_{VOL}$	50 k 25 k	200 k	-	25 k 25k	200 k	-	V/V
Output Voltage Swing $R_L > 5.0k\Omega$ , $T_{low} < T_A < T_{high}$	$V_O$	$\pm 1.9$	$\pm 2.1$	-	$\pm 2.0$	$\pm 2.1$	-	V
Output Resistance	$r_o$	-	1.0	-	-	1.0	-	k $\Omega$
Output Short-Circuit Current	$I_{OS}$	-	5.0	-	-	5.0	-	mA
Common-Mode Rejection Ratio $R_S < 10k\Omega$ , $T_{low} < T_A < T_{high}$	CMRR	70	86	-	70	86	-	dB
Supply Voltage Rejection Ratio $R_S < 10k\Omega$ , $T_{low} < T_A < T_{high}$	PSRR	-	25	150	-	25	200	$\mu V/V$
Supply Current $T_A = +25^\circ C$ $T_{low} < T_A < T_{high}$	$I_{CC}$ , $I_{EE}$	-	130	160	-	130	170 180	$\mu A$
Power Dissipation $T_A = +25^\circ C$ $T_{low} < T_A < T_{high}$	$P_D$	-	780	960	-	780	1020 1080	$\mu W$
Transient Response (Unity Gain) $V_{in} = 20mV$ , $R_L > 5.0k\Omega$ , $C_L = 100pF$ Rise Time Overshoot	$t_{LH}$ OS	-	0.6 5.0	-	-	0.6 5.0	-	$\mu s$ %
Slew Rate ( $R_L > 5.0k\Omega$ )	$S_R$	-	0.35	-	-	0.35	-	V/ $\mu s$

\* $T_{low} = -65^\circ C$  for MC1776  
0 $^\circ C$  for MC1776C

$T_{high} = +125^\circ C$  for MC1776  
+70 $^\circ C$  for MC1776C

MC1776, MC1776C

ELECTRICAL CHARACTERISTICS (V<sub>CC</sub> = +15 V, V<sub>EE</sub> = -15 V, I<sub>set</sub> = 1.5 μA, T<sub>A</sub> = +25°C unless otherwise noted.)

Characteristic	Symbol	MC1776			MC1776C			Unit
		Min	Typ	Max	Min	Typ	Max	
Input Offset Voltage (R <sub>S</sub> ≤ 10 kΩ) T <sub>A</sub> = +25°C T <sub>low</sub> ≤ T <sub>A</sub> ≤ T <sub>high</sub> *	V <sub>IO</sub>	-	2.0	5.0	-	2.0	6.0	mV
Offset Voltage Adjustment Range	V <sub>IOR</sub>	-	9.0	-	-	9.0	-	mV
Input Offset Current T <sub>A</sub> = +25°C T <sub>A</sub> = T <sub>high</sub> T <sub>A</sub> = T <sub>low</sub>	I <sub>IO</sub>	-	0.7	3.0	-	0.7	6.0	nA
Input Bias Current T <sub>A</sub> = +25°C T <sub>A</sub> = T <sub>high</sub> T <sub>A</sub> = T <sub>low</sub>	I <sub>IB</sub>	-	2.0	7.5	-	2.0	10	nA
Input Resistance	r <sub>i</sub>	-	50	-	-	50	-	MΩ
Input Capacitance	c <sub>i</sub>	-	2.0	-	-	2.0	-	pF
Input Voltage Range T <sub>low</sub> ≤ T <sub>A</sub> ≤ T <sub>high</sub>	V <sub>ID</sub>	±10	-	-	±10	-	-	V
Large Signal Voltage Gain R <sub>L</sub> ≥ 75 kΩ, V <sub>O</sub> = ±10 V, T <sub>A</sub> = +25°C R <sub>L</sub> ≥ 75 kΩ, V <sub>O</sub> = ±10 V, T <sub>low</sub> ≤ T <sub>A</sub> ≤ T <sub>high</sub>	AVOL	200 k 100 k	400 k -	- -	50 k 50 k	400 k -	- -	V/V
Output Voltage Swing R <sub>L</sub> ≥ 75 kΩ, T <sub>A</sub> = +25°C R <sub>L</sub> ≥ 75 kΩ, T <sub>low</sub> ≤ T <sub>A</sub> ≤ T <sub>high</sub>	V <sub>O</sub>	±12 ±10	±14 -	- -	±12 ±10	±14 -	- -	V
Output Resistance	r <sub>o</sub>	-	5.0	-	-	5.0	-	kΩ
Output Short-Circuit Current	I <sub>OS</sub>	-	3.0	-	-	3.0	-	mA
Common-Mode Rejection Ratio R <sub>S</sub> ≤ 10 kΩ, T <sub>low</sub> ≤ T <sub>A</sub> ≤ T <sub>high</sub>	CMRR	70	90	-	70	90	-	dB
Supply Voltage Rejection Ratio R <sub>S</sub> ≤ 10 kΩ, T <sub>low</sub> ≤ T <sub>A</sub> ≤ T <sub>high</sub>	PSRR	-	25	150	-	25	200	μV/V
Supply Current T <sub>A</sub> = +25°C T <sub>low</sub> ≤ T <sub>A</sub> ≤ T <sub>high</sub>	I <sub>CC</sub> , I <sub>EE</sub>	-	20	25	-	20	30	μA
Power Dissipation T <sub>A</sub> = +25°C T <sub>low</sub> ≤ T <sub>A</sub> ≤ T <sub>high</sub>	P <sub>D</sub>	-	-	0.75	-	-	0.9	mW
Transient Response (Unity Gain) V <sub>in</sub> = 20 mV, R <sub>L</sub> ≥ 5.0 kΩ, C <sub>L</sub> = 100 pF								
Rise Time	t <sub>TLH</sub>	-	1.6	-	-	1.6	-	μs
Overshoot	OS	-	0	-	-	0	-	%
Slew Rate (R <sub>L</sub> ≥ 5.0 kΩ)	S <sub>R</sub>	-	0.1	-	-	0.1	-	V/μs

\*T<sub>low</sub> = -55°C for MC1776      T<sub>high</sub> = +125°C for MC1776  
 0°C for MC1776C              +70°C for MC1776C

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ELECTRICAL CHARACTERISTICS (V<sub>CC</sub> = +15 V, V<sub>EE</sub> = -15 V, I<sub>set</sub> = 15 μA, T<sub>A</sub> = +25°C unless otherwise noted.)

Characteristic	Symbol	MC1776			MC1776C			Unit
		Min	Typ	Max	Min	Typ	Max	
Input Offset Voltage (R <sub>S</sub> < 10 kΩ) T <sub>A</sub> = +25°C T <sub>low</sub> * < T <sub>A</sub> < T <sub>high</sub> *	V <sub>IO</sub>	-	2.0	5.0	-	2.0	6.0	mV
		-	-	6.0	-	-	7.5	
Offset Voltage Adjustment Range	V <sub>IOR</sub>	-	18	-	-	18	-	mV
Input Offset Current T <sub>A</sub> = +25°C	I <sub>IO</sub>	-	2.0	15	-	2.0	25	nA
T <sub>A</sub> = T <sub>high</sub>		-	-	15	-	-	25	
T <sub>A</sub> = T <sub>low</sub>		-	-	40	-	-	40	
Input Bias Current T <sub>A</sub> = +25°C	I <sub>IB</sub>	-	15	50	-	15	50	nA
T <sub>A</sub> = T <sub>high</sub>		-	-	50	-	-	50	
T <sub>A</sub> = T <sub>low</sub>		-	-	120	-	-	100	
Input Resistance	r <sub>i</sub>	-	5.0	-	-	5.0	-	MΩ
Input Capacitance	c <sub>i</sub>	-	2.0	-	-	2.0	-	pF
Input Voltage Range T <sub>low</sub> < T <sub>A</sub> < T <sub>high</sub>	V <sub>ID</sub>	±10	-	-	±10	-	-	V
Large Signal Voltage Gain R <sub>L</sub> > 5.0 kΩ, V <sub>O</sub> = ±10 V, T <sub>A</sub> = +25°C R <sub>L</sub> > 75 kΩ, V <sub>O</sub> = ±10 V, T <sub>low</sub> < T <sub>A</sub> < T <sub>high</sub>	A <sub>VOL</sub>	100 k 75 k	400 k -	- -	50 k 50 k	400 k -	- -	V/V
Output Voltage Swing R <sub>L</sub> > 5.0 kΩ, T <sub>A</sub> = +25°C R <sub>L</sub> > 75 kΩ, T <sub>low</sub> < T <sub>A</sub> < T <sub>high</sub>	V <sub>O</sub>	±10 ±10	±13 -	- -	±10 ±10	±13 -	- -	V
Output Resistance	r <sub>o</sub>	-	1.0	-	-	1.0	-	kΩ
Output Short-Circuit Current	I <sub>OS</sub>	-	12	-	-	12	-	mA
Common-Mode Rejection Ratio R <sub>S</sub> < 10 kΩ, T <sub>low</sub> < T <sub>A</sub> < T <sub>high</sub>	CMRR	70	90	-	70	90	-	dB
Supply Voltage Rejection Ratio R <sub>S</sub> < 10 kΩ, T <sub>low</sub> < T <sub>A</sub> < T <sub>high</sub>	PSRR	-	25	150	-	25	200	μV/V
Supply Current T <sub>A</sub> = +25°C T <sub>low</sub> < T <sub>A</sub> < T <sub>high</sub>	I <sub>CC</sub> , I <sub>EE</sub>	-	160	180 200	-	160	190 200	μA
Power Dissipation T <sub>A</sub> = +25°C T <sub>low</sub> < T <sub>A</sub> < T <sub>high</sub>	P <sub>D</sub>	-	-	5.4 6.0	-	-	5.7 6.0	mW
Transient Response (Unity Gain) V <sub>in</sub> = 20 mV, R <sub>L</sub> ≥ 5.0 kΩ, C <sub>L</sub> = 100 pF								
Rise Time	t <sub>TLH</sub>	-	0.35	-	-	0.35	-	μs
Overshoot	OS	-	10	-	-	10	-	%
Slew Rate (R <sub>L</sub> > 5.0 kΩ)	S <sub>R</sub>	-	0.8	-	-	0.8	-	V/μs

\*T<sub>low</sub> = -55°C for MC1776  
 0°C for MC1776C  
 T<sub>high</sub> = +125°C for MC1776  
 +70°C for MC1776C

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TYPICAL CHARACTERISTICS

( $T_A = +25^\circ\text{C}$  unless otherwise noted.)

FIGURE 1 - SET CURRENT versus SET RESISTOR

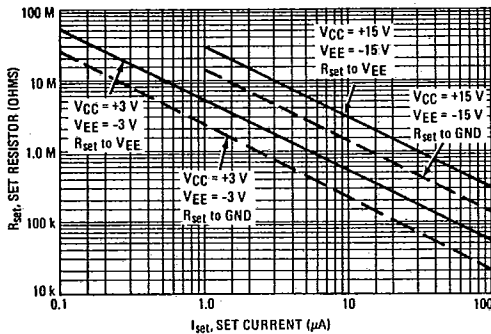


FIGURE 2 - POSITIVE STANDBY SUPPLY CURRENT versus SET CURRENT

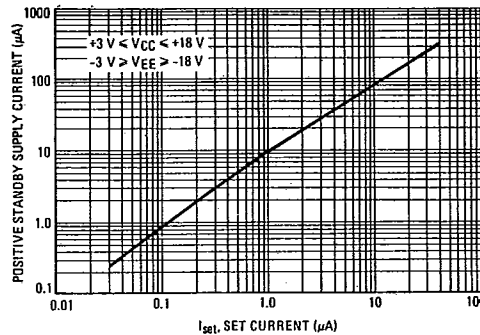


FIGURE 3 - OPEN-LOOP GAIN versus SET CURRENT

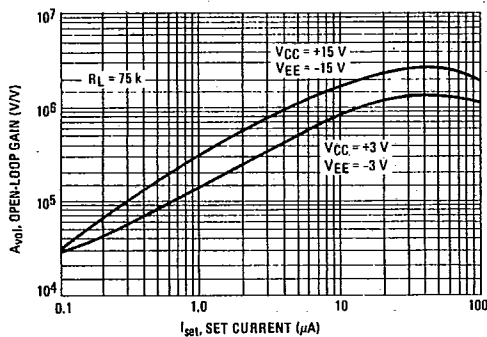


FIGURE 4 - INPUT BIAS CURRENT versus SET CURRENT

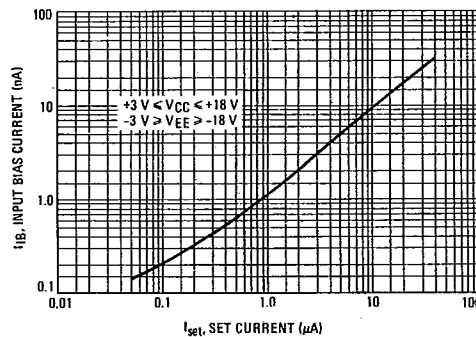


FIGURE 5 - INPUT BIAS CURRENT versus AMBIENT TEMPERATURE

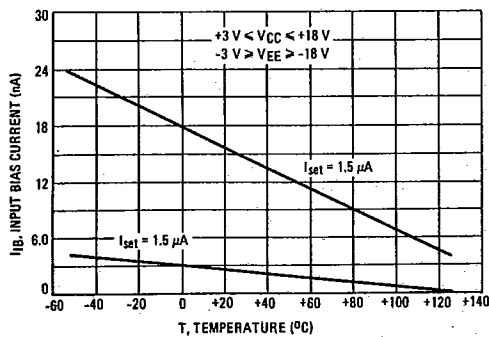
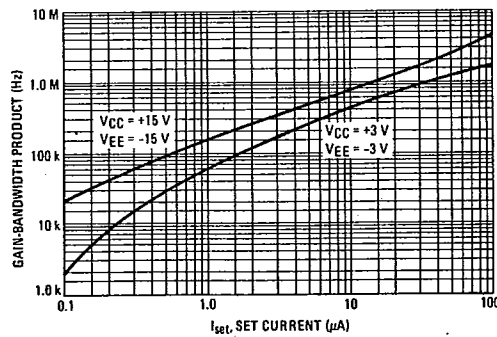


FIGURE 6 - GAIN-BANDWIDTH PRODUCT (GBW) versus SET CURRENT



MC1776, MC1776C

TYPICAL CHARACTERISTICS (continued)  
 (T<sub>A</sub> = +25°C unless otherwise noted.)

FIGURE 7 — OUTPUT VOLTAGE SWING  
 versus LOAD RESISTANCE

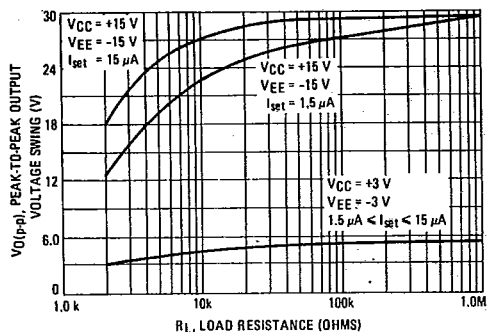
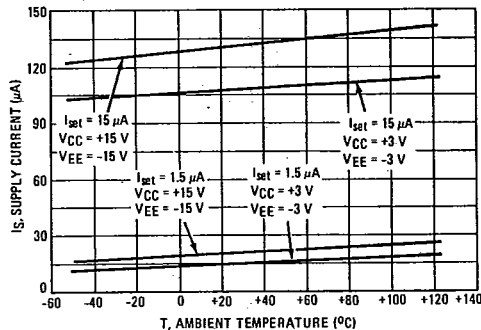


FIGURE 8 — SUPPLY CURRENT  
 versus AMBIENT TEMPERATURE



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FIGURE 9 — OUTPUT SWING  
 versus SUPPLY VOLTAGE

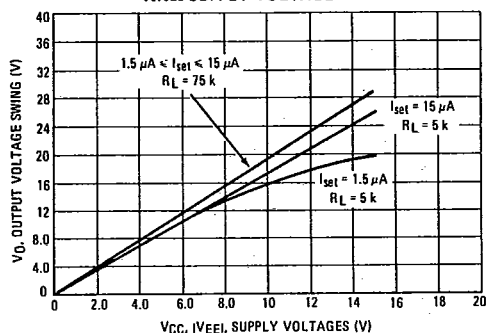


FIGURE 10 — SLEW RATE  
 versus SET CURRENT

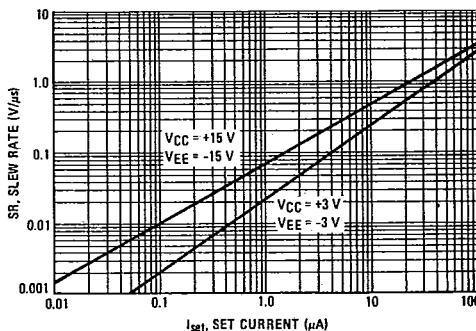


FIGURE 11 — INPUT NOISE VOLTAGE  
 versus SET CURRENT

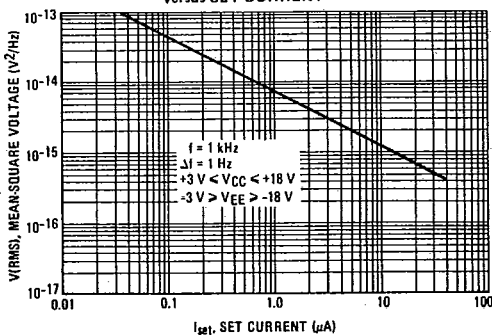
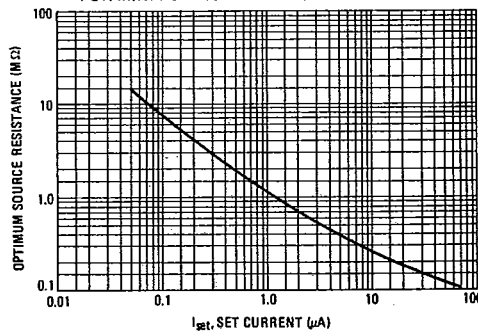


FIGURE 12 — OPTIMUM SOURCE RESISTANCE  
 FOR MINIMUM NOISE versus SET CURRENT



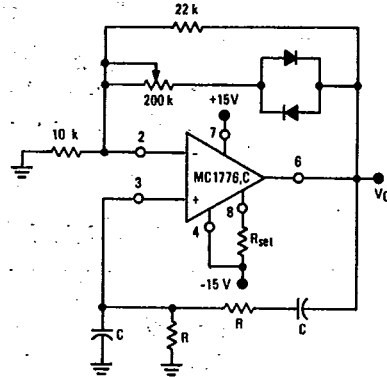


MC1776, MC1776C

APPLICATIONS INFORMATION

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FIGURE 13 - WIEN BRIDGE OSCILLATOR

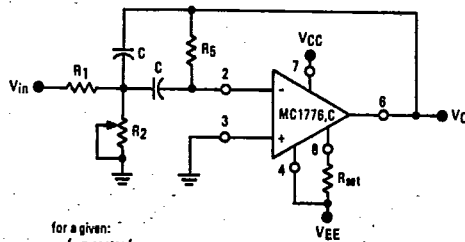


$$f_0 = \frac{1}{2\pi RC}$$

(for  $f_0 = 1.0 \text{ kHz}$ )

$R = 16 \text{ k}\Omega$   
 $C = 0.01 \mu\text{F}$

FIGURE 14 - MULTIPLE FEEDBACK BANDPASS FILTER



for a given:  
 $f_0$  = center frequency  
 $A(f_0)$  = Gain at center frequency  
 $Q$  = quality factor  
 Choose a value for C, then

$$R_5 = \frac{Q}{\pi f_0 C}$$

$$R_1 = \frac{R_5}{2A(f_0)}$$

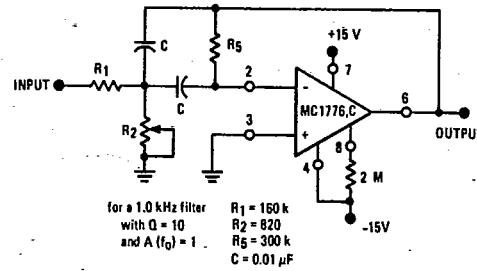
$$R_2 = \frac{R_1 R_5}{4Q^2 R_1 - R_5}$$

To obtain less than 10% error from the operational amplifier:

$$\frac{Q_0 f_0}{GBW} < 0.1$$

where  $f_0$  and GBW are expressed in Hz. GBW is available from Figure 6 as a function of Set Current,  $I_{set}$ .

FIGURE 15 - MULTIPLE FEEDBACK BANDPASS FILTER (1.0 kHz)



for a 1.0 kHz filter  
 with  $Q = 10$   
 and  $A(f_0) = 1$

$R_1 = 160 \text{ k}\Omega$   
 $R_2 = 620 \text{ k}\Omega$   
 $R_5 = 300 \text{ k}\Omega$   
 $C = 0.01 \mu\text{F}$

FIGURE 16 - GATED AMPLIFIER

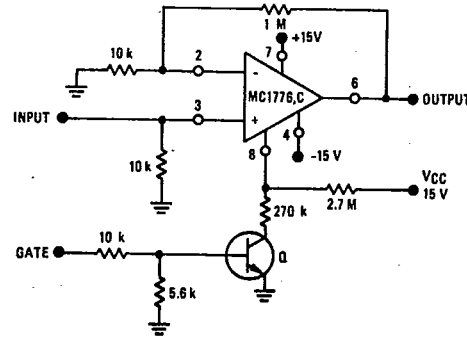


FIGURE 17 - HIGH INPUT IMPEDANCE AMPLIFIER

